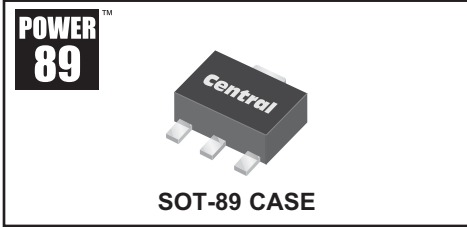


CXT3090L
SURFACE MOUNT
LOW $V_{CE(SAT)}$
NPN SILICON POWER TRANSISTOR



www.centrasemi.com

DESCRIPTION:

The CENTRAL SEMICONDUCTOR CXT3090L is a Low $V_{CE(SAT)}$ NPN Transistor in a Power SOT-89 surface mount package, designed for DC-DC converters for mobile systems and LAN cards, motor control, power management and strobe flash units.

MARKING: FULL PART NUMBER

MAXIMUM RATINGS: ($T_A=25^\circ\text{C}$)

Collector-Base Voltage
 Collector-Emitter Voltage
 Emitter-Base Voltage
 Continuous Collector Current
 Peak Collector Current
 Power Dissipation
 Operating and Storage Junction Temperature
 Thermal Resistance

SYMBOL		UNITS
V_{CBO}	45	V
V_{CEO}	15	V
V_{EBO}	6.0	V
I_C	3.0	A
I_{CM}	5.0	A
P_D	1.2	W
T_J, T_{stg}	-65 to +175	$^\circ\text{C}$
θ_{JA}	125	$^\circ\text{C/W}$

ELECTRICAL CHARACTERISTICS: ($T_A=25^\circ\text{C}$)

SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
I_{CBO}	$V_{CB}=20\text{V}$			100	nA
I_{EBO}	$V_{EB}=5.0\text{V}$			100	nA
BV_{CBO}	$I_C=10\mu\text{A}$	45			V
BV_{CEO}	$I_C=10\text{mA}$	15			V
BV_{EBO}	$I_E=10\mu\text{A}$	6.0			V
$V_{CE(SAT)}$	$I_C=100\text{mA}, I_B=1.0\text{mA}$		30	50	mV
$V_{CE(SAT)}$	$I_C=1.0\text{A}, I_B=20\text{mA}$		60	150	mV
$V_{CE(SAT)}$	$I_C=2.0\text{A}, I_B=200\text{mA}$		85	200	mV
$V_{CE(SAT)}$	$I_C=3.0\text{A}, I_B=60\text{mA}$		145	300	mV
h_{FE}	$V_{CE}=2.0\text{V}, I_C=500\text{mA}$	200			
h_{FE}	$V_{CE}=2.0\text{V}, I_C=1.0\text{A}$	200			
h_{FE}	$V_{CE}=2.0\text{V}, I_C=3.0\text{A}$	150			
C_{ob}	$V_{CB}=10\text{V}, f=1.0\text{MHz}$			100	pF
f_T	$V_{CE}=10\text{V}, I_C=500\text{mA}$	100			MHz

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SOT-89 CASE - MECHANICAL OUTLINE



LEAD CODE:

- 1) Emitter
- 2) Collector
- 3) Base

MARKING:
FULL PART NUMBER

DIMENSIONS				
SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.055	0.067	1.40	1.70
B	4°		4°	
C	0.014	0.018	0.35	0.46
D	0.173	0.185	4.40	4.70
E	0.064	0.074	1.62	1.87
F	0.146	0.177	3.70	4.50
G	0.090	0.106	2.29	2.70
H	0.028	0.051	0.70	1.30
J	0.014	0.019	0.36	0.48
K	0.017	0.023	0.44	0.58
L	0.059		1.50	
M	0.118		3.00	

SOT-89 (REV: R4)

R5 (23-February 2010)

OUTSTANDING SUPPORT AND SUPERIOR SERVICES



PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- Consolidated shipping options
- Custom bar coding for shipments
- Custom product packing

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- Environmental regulation compliance
- Customer specific screening
- Up-screening capabilities
- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- Application and design sample kits
- Custom product and package development

REQUESTING PRODUCT PLATING

1. If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
2. If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

CONTACT US

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